Consumer SSD E2000 Series

Introduction

Consumer SSD E2000 adopts M.2 interface, advanced SSD control computing chip and 3D NAND flash to effectively improve R/W speed and ensure data security.

It applies to personal computer and small-size proxy server to providing stable and high-speed service. It can also improve the high-end gaming experience and 3D graphics editing performance.

Available Models

HS-SSD-E2000 / 256GB

HS-SSD-E2000 / 512GB

HS-SSD-E2000 / 1024GB

Typical Application

- PC (notebook and desktop)
- Small-size proxy sever

Features and Functions

- **High R/W Speed**
  Supports PCIe and NVMe
  Max. read speed up to 3500 MB/s
- **3D NAND**
  Adopts 3D NAND flash to optimize capacity, performance and stability
- **Shockproof**
  No mechanical structure
  Adopts electronic chips control
  High data security
- **M.2 Interface**
  Small and portable, easy to install

Specifications

Model		HS-SSD-E2000		
Capacity		256 GB	512 GB	1024 GB
Form Factor		M.2 (NGFF)		
Interface		PCIe Gen 3 x 4, NVMe		
DRAM Cache Memory		256 MB	512MB	1 GB
Dimensions		80.15 mm × 22.15 mm × 2.38 mm		
Max. sequential 128 K read speed❶		3100 MB/s	3300 MB/s	3500 MB/s
Max. sequential 128 K write speed		1300 MB/s	2100 MB/s	3000 MB/s
Max. random 4 K read IOPS❷		187 K	369 K	600 K
Max. random 4 K write IOPS		245 K	470 K	600 K
Power consumption❸	Read (RMS max.)	6.4 W	7 W	7.2 W
	Write (RMS max.)	3.9 W	5 W	6.1 W
Endurance (TBW)❹		380 TB	800 TB	1665 TB
NAND flash memory		3D TLC		
Weight		≤ 8 g		
MTBF (Mean Time between Failures)❺		1,500,000 h		
Operation temperature		0 °C to 70 °C (32 °F to 158 °F)		
Storage temperature		-40 °C to +85 °C (-40 °F to +185 °F)		
Operation humidity		5% to 95% (no condensation)		
Limited warranty period		3 years		

**: Performance test is performed in a specific testing environment. Any change of computer system, operation system, hardware, software, or functions will influence the test result.*

❶❷*: Performance in the specifications is tested based on CrystalDiskMark.*

❸*: Power consumption may differ according to flash configuration and platform. Power consumptions are measured by using CrystalDiskMark 1000 MB to test sequential R/W 5 times. Power consumptions are measured when sequential Read [1/5] to [5/5] and sequential Write [1/5] to [5/5].*

❹*: The TBW value is calculated based on Workload of JEDC 218B/219A standard.*

❺*: The MTBF value is calculated based on the functional failure rate of JEDC 218B/219A standard.*

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